



EPC2108ENGRT Information

Part Number EPC2108ENGRT

Manufacturer EPC

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Arrays

Description TRANS GAN 3N-CH BUMPED DIE

Package 9-VFBGA

For the pricing/inventory/lead time, please contact

us

For Reference Only

Website: https://www.heisener.com
E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









EPC2108ENGRT Specifications

Manufacturer Part Number	EPC2108ENGRT	
Manufacturer	EPC	
Category	Discrete Semiconductor Products	
	Transistors - FETs, MOSFETs - Arrays	
Package	9-VFBGA	
Series	eGaN?	
FET Type	3 N-Channel (Half Bridge + Synchronous Bootstrap)	
FET Feature	GaNFET (Gallium Nitride)	
Drain to Source Voltage (Vdss)	60V, 100V	
Current - Continuous Drain (Id) @ 25°C	1.7A, 500mA	
Rds On (Max) @ Id, Vgs	190 mOhm @ 2.5A, 5V, 3.3 Ohm @ 2.5A, 5V	
Vgs(th) (Max) @ Id	2.5V @ 100μA, 2.5V @ 20μA	
Gate Charge (Qg) (Max) @ Vgs	0.22nC @ 5V, 0.044nC @ 5V	
Input Capacitance (Ciss) (Max) @ Vds	22pF @ 30V, 7pF @ 30V	
Power - Max	-	
Operating Temperature	-40°C ~ 150°C (TJ)	
Mounting Type	Surface Mount	
Package / Case	9-VFBGA	
Supplier Device Package	9-BGA (1.35x1.35)	
		Report errors?

EPC2108ENGRT Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

EPC2108ENGRT Payment Methods



















EPC2108ENGRT Shipping Methods













If you have any question about EPC2108ENGRT, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com